

# Parametric Amplifiers for Readout of Low-Temperature Detectors

Completed Technology Project (2014 - 2015)



## Project Introduction

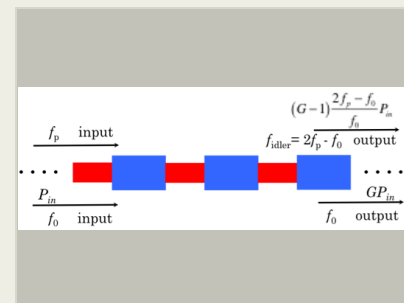
This project aims to make microwave parametric amplifiers with high gain, large bandwidth, ultra-low noise, and low power dissipation. Our amplifiers are designed to have greatly improved gain characteristics over similar experimental devices. The amplifiers would enable revolutionary astrophysics instruments with far-infrared photon-counting detectors or high-resolution x-ray microcalorimeters.

Our goal is to build microwave amplifiers with near quantum-limited sensitivity, octave or greater bandwidth, gain > 20 dB for signals of frequency 1 – 10 GHz, and power dissipation less than 1 microwatt at a 100 mK operating temperature, or 1 milliwatt at 4 K. Such amplifiers would find immediate application in efforts to develop far infrared instruments based on Microwave Kinetic Inductance Detectors (MKIDs), or in x-ray microcalorimeters with microwave SQUID amplifier (mSQUID) readout systems.

Existing state-of-the-art broadband HEMT amplifiers used so far for MKID or mSQUID readout have noise temperatures about 1 – 10 K. The noise of HEMTs, while low enough for many applications, limits sensitivity of MKIDs. In addition, the power dissipation of cryogenic HEMTs is not as low as desired in a space-based instrument. The new amplifiers in this project would be of great benefit in high performance instrument concepts involving MKID or mSQUID arrays for astrophysics missions.

## Anticipated Benefits

Applicable in ground-based demonstration instruments for astrophysics. Provide lower amplifier noise temperature and lower power dissipation than state-of-the art High Electron Mobility Transistors over a wide bandwidth.



Parametric Amplifier Sketch

## Table of Contents

Project Introduction	1
Anticipated Benefits	1
Primary U.S. Work Locations and Key Partners	2
Images	2
Organizational Responsibility	2
Project Management	2
Links	3
Project Website:	3
Technology Maturity (TRL)	3
Technology Areas	3

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## Primary U.S. Work Locations and Key Partners



## Organizational Responsibility

**Responsible Mission Directorate:**

Mission Support Directorate (MSD)

**Lead Center / Facility:**

Goddard Space Flight Center (GSFC)

**Responsible Program:**

Center Independent Research &amp; Development: GSFC IRAD

## Project Management

**Program Manager:**

Peter M Hughes

**Project Manager:**

Terence A Doiron

**Principal Investigator:**

Thomas R Stevenson

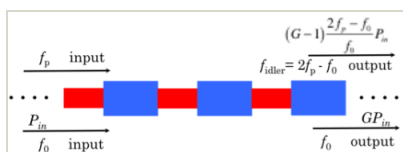
**Co-Investigators:**Negar Ehsan  
Megan E Eckart  
Ari D Brown

Organizations Performing Work	Role	Type	Location
★ Goddard Space Flight Center (GSFC)	Lead Organization	NASA Center	Greenbelt, Maryland

## Primary U.S. Work Locations

Maryland

## Images



### Parametric Amplifiers for Readout of Low-Temperature Detectors Project

Parametric Amplifier Sketch

(<https://techport.nasa.gov/image/16629>)

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## Links

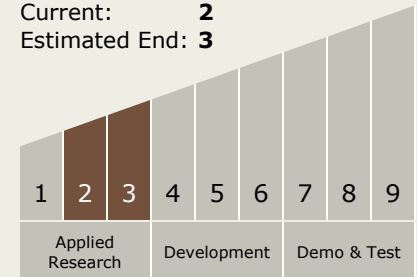
GSC-17504-1  
(no url provided)

## Project Website:

<http://aetd.gsfc.nasa.gov/>

## Technology Maturity (TRL)

Start: **2**  
Current: **2**  
Estimated End: **3**



## Technology Areas

### Primary:

- TX08 Sensors and Instruments
  - └ TX08.1 Remote Sensing Instruments/Sensors
    - └ TX08.1.2 Electronics